

# 國立中央大學 107 學年度碩士班考試入學試題

所別： 光電科學與工程學系 碩士班 不分組(一般生)

共 2 頁 第 1 頁

科目： 電子學

本科考試可使用計算器，廠牌、功能不拘。

\*請在答案卷(卡)內作答

7% 1. Please explain the concept of holes as much as you can.

2. An abrupt planar semiconductor  $p^+ - n$  junction at  $T = 300\text{ K}$  is uniformly doped with an acceptor concentration  $N_a = 2 \times 10^{17}\text{ cm}^{-3}$  and an unknown donor concentration of  $N_d$ . The dielectric constant of the intrinsic material is  $\epsilon_s = 11.7$  ( $\epsilon_0 \sim 8.854 \times 10^{-12}\text{ F/m}$ ) and the cross-sectional area of the  $p^+ - n$  junction is  $10^{-5}\text{ cm}^2$ . An inductance of  $3.306\text{ mH}$  is connected in parallel with the  $p^+ - n$  diode. At a reverse-biased voltage  $V_R = 1\text{ V}$ , the resonant frequency of the  $LC$  circuit (assume the resistance is negligibly small) is  $f = 8.85\text{ MHz}$  and 99 percent of the total space charge width is in the  $n$  region. Answer the following questions:

5% (a) What is the capacitance per unit area of this  $p^+ - n$  junction?

8% (b) Determine  $N_d$

10% (c) Given the expression for the junction width  $W$

$$W = \left\{ \frac{2\epsilon_s (V_{bi} + V_R)}{q} \left[ \frac{N_a + N_d}{N_a N_d} \right] \right\}^{1/2},$$

where  $q = 1.60 \times 10^{-19}\text{ C}$ . Determine the built-in voltage  $V_{bi}$  at  $V_R = 1\text{ V}$ .

3. The BJT amplifier shown in Fig. 1 uses a BJT having  $\beta = 110$ . All capacitors are assumed to be sufficiently large.

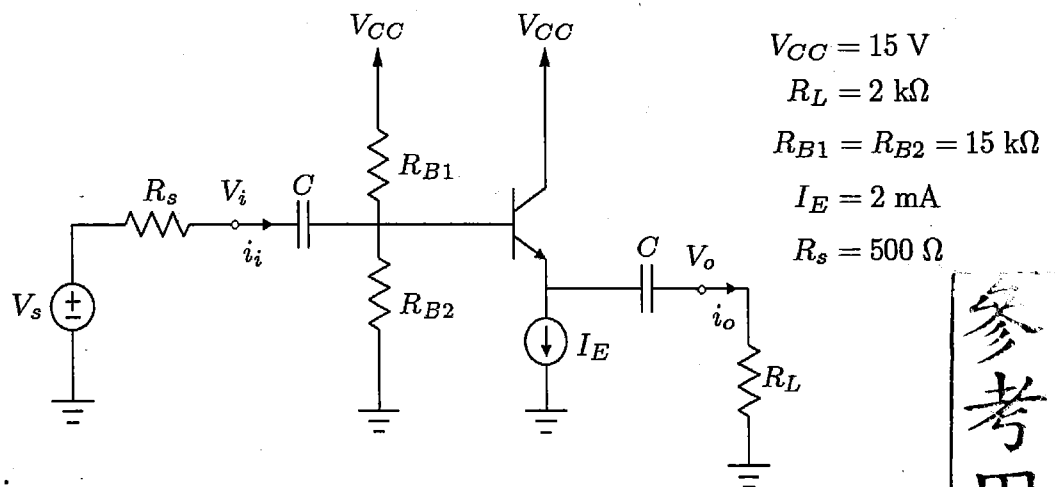


Fig. 1:

5% (a) Determine the DC voltage at the emitter  $V_E$ .

5% (b) Draw the small-signal model of this amplifier with all parameter values calculated and labeled properly.

10% (c) Find out the small-signal current gain  $i_o / i_i$ .

參考用

注意:背面有試題

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4. For the circuit in Fig. 2,

- 10% (a) derive the transfer function  $T \equiv v_o / v_i$ ;  
 10% (b) sketch the transfer characteristic of the circuit ( $v_o$  versus  $v_i$ ).

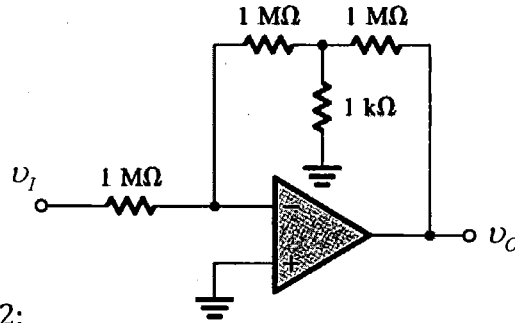


Fig. 2:

5. Consider the phase-shift oscillator in Figure 3,

- 10% (a) find the oscillation frequency of  $v_o$ ;  
 5% (b) determine the condition for oscillation.

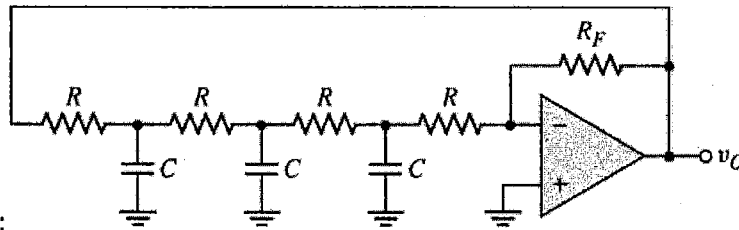


Fig. 3:

6. Fig. 4 shows the circuit for a constant current driver. The normal driving condition for LED is set at 750mA. For  $Q_1$ ,  $\beta = 100$ ,  $V_{BE} = 0.75V$ ,  $V_{CE,sat} = 0.2V$  and  $V_{CE,breakdown} = 50V$ .

- 5% (a) Derive the relation between the reference voltage  $V_1$  and the current through LED.  
 5% (b) What are the proper values for the resistor  $R_1$  and the reference voltage  $V_1$ ?  
 5% (c) As under 750mA driving, the forward voltage of the LED is 2.5V. As the constant current driver sustains in normal operation, what is the maximal number of the LEDs in series between VCC and  $Q_1$ ?

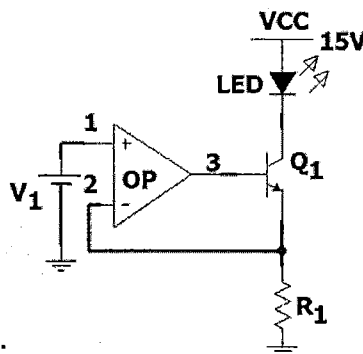


Fig. 4:

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